

The Leader in High Temperature Semiconductor Solutions

Version: 1.3

CHT-AMALTHEA Preliminary Datasheet

High Temperature 80V / 3A Dual Diode Common Anode, Common Cathode and Dual Series

General description

The CHT-AMATHEA is a Medium Power 80V/3A dual-diode designed to achieve high performance in an extremely wide temperature range: typical operation temperature goes from -55°C to 225°C.

3 product flavours are available:

- Common Anode
- Common Cathode
- Dual Series

The CHT-AMALTHEA is available in a metal can TO-257 package.

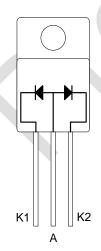
Applications

- Rectification
- Free-wheeling
- Clamping
- General purpose

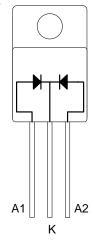
Features

- Specified from -55 to +225°C (Tj)
- Reverse voltage: $V_R = 80V$ (max)
- Forward current: I_F = 3A (max @ 225°C (Tj) and VF = 1.85V)
- Forward voltage: V_F = 1.7V (typ. @ 25 (Tj) and IF = 3A)
- Junction capacitance: C_j=36 pF (typ.
 @ VR = 80V)
- Package: Hermetically-sealed metal can TO-257 Isolated case

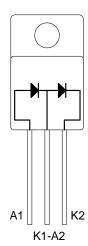
Pinout



Common Anode configuration



Common Cathode configuration



Dual Series configuration

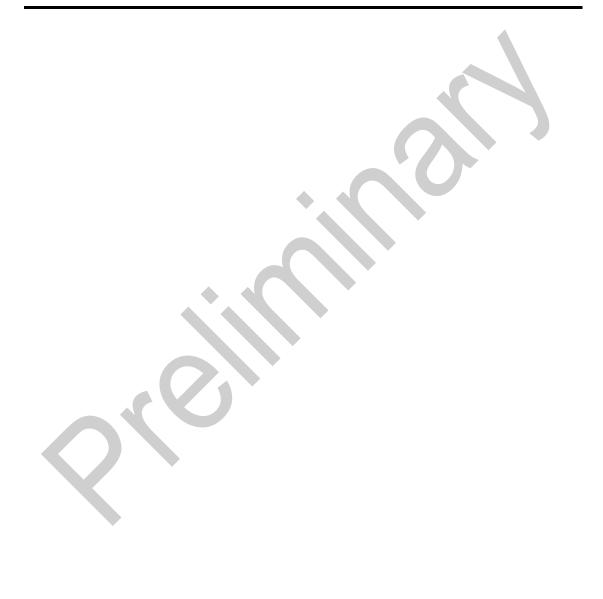
Absolute Maximum Ratings Operating Conditions

Reverse voltage V_{R} 80V Reverse voltage V_R 80V Peak Repetitive Forward current I_{FRM} 4A Continuous forward current I_F 0A to 3A Power dissipation T_c=25°C 12W Junction temperature -55°C to +225°C Junction temperature T_i 250°C

ESD Rating

Human Body Model 2kV

Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Frequent or extended exposure to absolute maximum rating conditions or above may affect device reliability.



Electrical characteristics (single diode) Unless otherwise stated, $T_j = 25^{\circ}C$. Bold figures point out values valid over the whole temperature range ($T_j = -55^{\circ}C$ to +225°C).

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Compared voltage	VF	I _F =2A, T _j =25°C		1.48		V
Forward voltage	VF	I _F =2A, T _j =225°C		1.53		V
Reverse leakage current	I _R	V _R =80V, T _j =25°C		20		nA
Neverse leakage current	¹R	V _R =80V, T _j =225°C		40		μΑ
Breakdown reverse voltage	V_{BR}		80			V
Junction capacitance	Cj	V _R =20V; T _i =25°C; f=1MHz V _R =40V; T _i =25°C; f=1MHz V _R =80V; T _i =25°C; f=1MHz		56 48 36		pF
Total capacitive charge	Q _C	$V_R = 80V; I_F = 1A$ di/dt= 50A/µs T_i =25°C		TBD		nC
Reverse recovery time ¹	t _{rr}	V _R = 80V		59		ns
Peak reverse recovery current	I _{rrp}	$I_F = 1A$ $T_a = 25$ °C		920		mA
Repetitive Peak Forward Surge Current	I _{FRM}	t_P = 8.3ms Half-Sine Wave T_a = 25°C		TBD	1	А
Case isolation		V_A or $V_K = 80V_{DC}$	1			GΩ

Thermal Characteristics

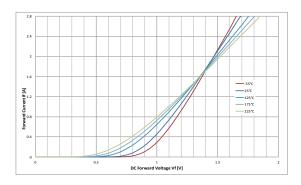
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Thermal resistance	Θ		>	ρ		°C/W
(junction-to-case, TO-257)	Θ ^{JC}			0		5

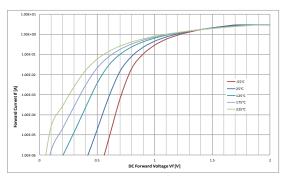
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 $^{^{1}}$ t_{rr} measured between points where current crosses zero and current reaches 10% of peak reverse recovery current

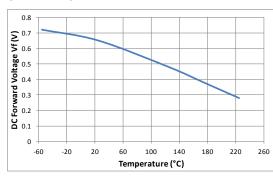


Typical Performance Characteristics (applicable to each diode)

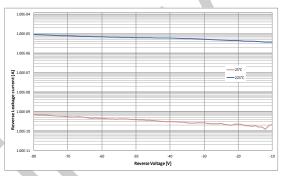




Forward current vs. forward voltage and temperature (linear scale)



Forward current vs. forward voltage and temperature (\log_{10} scale)



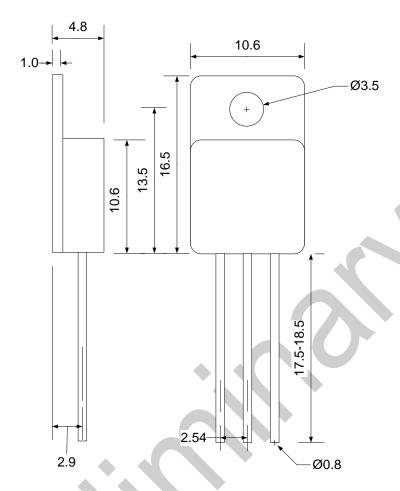
Forward voltage (at forward current $I_F=1mA$) vs. temperature

Reverse leakage current vs. reverse voltage and temperature





Package Dimensions



TO-257 package drawing (dimensions in mm)

Ordering Information

Common Anode

Product Name	Ordering Reference	Package	Marking
CHT-AMALTHEA	CHT-PLA0738A-TO257-T	TO-257	PLA0738A

Common Cathode

Product Name	Ordering Reference	Package	Marking
CHT-AMALTHEA	CHT-PLA0738B-TO257-T	TO-257	PLA0738B

Dual Series

Product Name	Ordering Reference	Package	Marking
CHT-AMALTHEA	CHT-PLA0738C-TO257-T	TO-257	PLA0738C



Contact & Ordering

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